

ADD-A-PAK Gen 7 Power Modules Schottky Rectifier, 200 A



PRODUCT SUMMARY			
I _{F(AV)}	200 A		
V _R	150 V		
Package	ADD-A-PAK Gen 7		
Circuit	Two diodes doubler circuit		

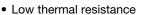
MECHANICAL DESCRIPTION

The ADD-A-PAK generation VII, new generation of ADD-A-PAK module, combines the excellent thermal performances obtained by the usage of exposed direct bonded copper substrate, with advanced compact simple package solution and simplified internal structure with minimized number of interfaces.

FEATURES

- 175 °C T_J operation
- · Low forward voltage drop
- High frequency operation
- UL approved file E78996





- · Designed and qualified for industrial level
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

BENEFITS

- · Excellent thermal performances obtained by the usage of exposed direct bonded copper substrate
- High surge capability
- · Easy mounting on heatsink

ELECTRICAL DESCRIPTION

The VS-VSKDS409/150 Schottky rectifier doubler module has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature.

Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	200	A		
V _{RRM}		150	V		
I _{FSM}	t _p = 5 μs sine	20 000	A		
V _F	200 A _{pk} , T _J = 125 °C	0.85	V		
T _J	Range	-55 to +175	°C		

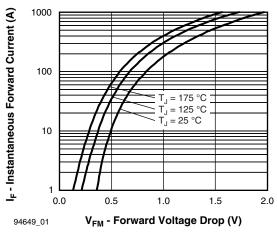
VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-VSKDS409/150	UNITS	
Maximum DC reverse voltage	V_{R}	150	V	
Maximum static peak reverse voltage	V_{RRM}	130	V	



ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _C = 105 °C, rectangular waveform		200	
Maximum peak one cycle	I _{FSM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with	20 000	Α
non-repetitive surge current		10 ms sine or 6 ms rect. pulse rated V _{RRM} applied		2300	
Non-repetitive avalanche energy	E _{AS}	T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH		15	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А
Maximum dynamic peak reverse voltage	V_{AV}	T _J = 25 °C, I _{AS} = 1.8 A, L = 10 mH		170	V

ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Marine of the second selection of the selection of the second selection of the		200 A	T _J = 25 °C	1.03	V
		400 A		1.33	
Maximum forward voltage drop	V_{FM}	200 A	T _J = 125 °C	0.85	V
		400 A		1.13	
Marine and a second	I _{RM}	T _J = 25 °C	V _R = Rated V _R	6	mA
Maximum reverse leakage current		T _J = 125 °C		85	IIIA
Maximum junction capacitance	C _T	$V_R = 5 V_{DC}$ (test signal range 100 kHz to 1 MHz), 25 °C		6000	pF
Typical series inductance	Ls	Measured lead to lead 5 mm from package body		5.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs
Maximum RMS insulation voltage	V _{INS}	50 Hz		3000 (1 min) 3600 (1 s)	V

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storag temperature range	е	T _J , T _{Stg}		-55 to +175	°C
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	0.32	°C/W
Typical thermal resistance, case to heatsink per module		R _{thCS}		0.1	C/VV
Approximate weight				75	g
Approximate weight				2.7	oz.
Mounting torque ± 10 %	to heatsink		A mounting compound is recommended and the torque should be rechecked after a period of 3 h to allow for the	4	Nm
	busbar		spread of the compound.	3	INIII
Case style			JEDEC [®]	TO-240AA co	ompatible





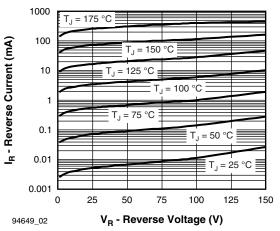


Fig. 2 - Typical Values of Reverse Current vs.
Reverse Voltage

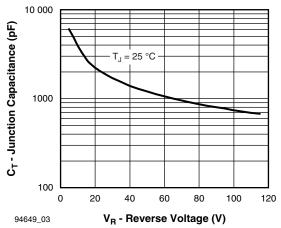


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

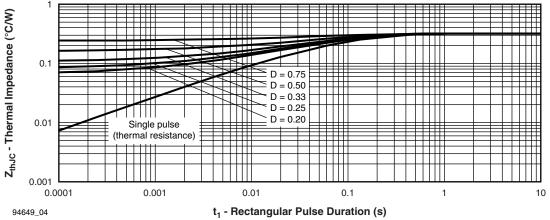


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Diode)

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Vishay Semiconductors

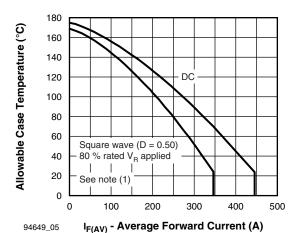


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

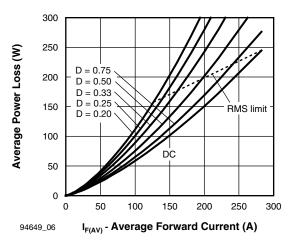


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

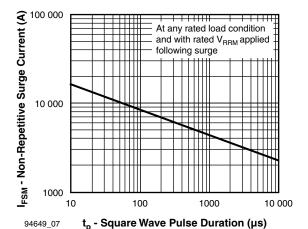


Fig. 7 - Maximum Non-Repetitive Surge Current

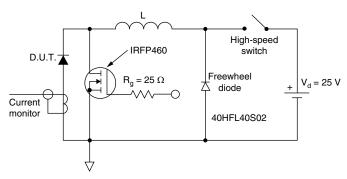


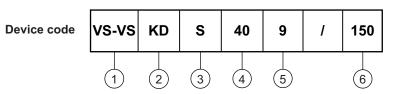
Fig. 8 - Unclamped Inductive Test Circuit

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM} at (I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R



ORDERING INFORMATION TABLE



1 - Vishay Semiconductors product

2 - Circuit configuration:

KD = ADD-A-PAK - 2 diodes in series

S = Schottky diode

4 - Average current rating (40 = 400 A) (1)

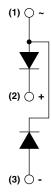
5 - Product silicon identification

6 - Voltage rating (150 = 150 V)

Note

(1) For KD configuration average current rating per module is 200 A

CIRCUIT CONFIGURATION

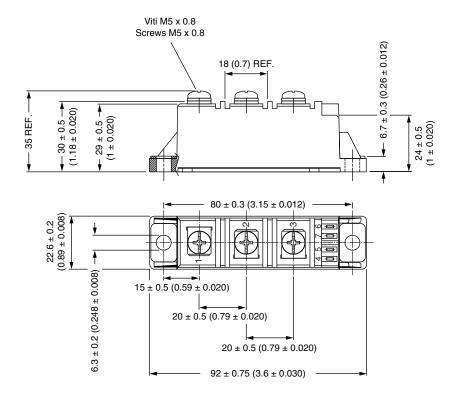


LINKS TO RELATED DOCUMENTS			
Dimensions	www.vishay.com/doc?95369		



ADD-A-PAK Generation VII - Diode

DIMENSIONS in millimeters (inches)





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